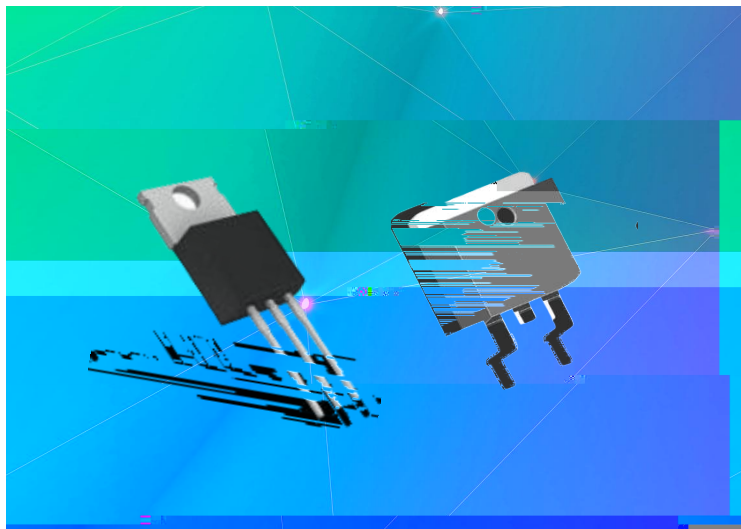


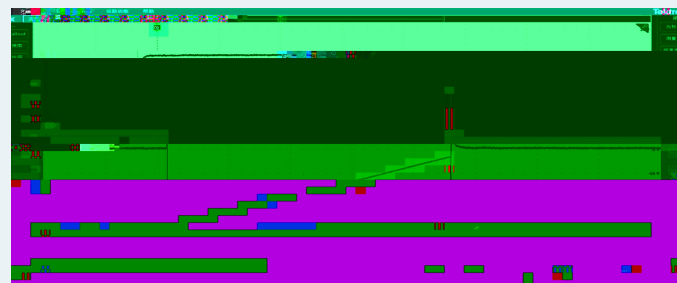
微沟



TO-220/TO-263

650V IGBT

- 1. 650V
- 3. 50A @ $T_c = 100$
- 4. I_{cm} 300A



Product Name	V_{CES} (V)	I_c (A)	$V_{GE(th)}$ (V)	$V_{CE(sat)}$ (V)	V_F (V)	P_d (W)	T_j
DGP50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175
DGB50N 65ATS2A	650V	50A	4.8	1.4	-	283	-40~175



1. Micro-trench process platform, a highly cost

New Product Announcement